

DS92CK16 3V BLVDS 1 to 6 Clock Buffer/Bus Transceiver

Check for Samples: [DS92CK16](#)

FEATURES

- Master/Slave Clock Selection in a Backplane Application
- 125 MHz Operation (Typical)
- 100 ps Duty Cycle Distortion (Typical)
- 50 ps Channel to Channel Skew (Typical)
- 3.3V Power Supply Design
- Glitch-free Power on at CLKI/O Pins
- Low Power Design (20 mA @ 3.3V Static)
- Accepts Small Swing (300 mV Typical) Differential Signal Levels
- Industrial Temperature Operating Range (-40°C to +85°C)
- Available in 24-pin TSSOP Packaging

DESCRIPTION

The DS92CK16 1 to 6 Clock Buffer/Bus Transceiver is a one to six CMOS differential clock distribution device utilizing Bus Low Voltage Differential Signaling (BLVDS) technology. This clock distribution device is designed for applications requiring ultra low power dissipation, low noise, and high data rates. The BLVDS side is a transceiver with a separate channel acting as a return/source clock.

The DS92CK16 accepts LVDS (300 mV typical) differential input levels, and translates them to 3V CMOS output levels. An output enable pin \overline{OE} , when high, forces all CLK_{OUT} pins high.

The device can be used as a source synchronous driver. The selection of the source driving is controlled by the $CrdCLK_{IN}$ and \overline{DE} pins. This device can be the master clock, driving the inputs of other clock I/O pins in a multipoint environment. Easy master/slave clock selection is achieved along a backplane.

Function Diagram and Truth Table

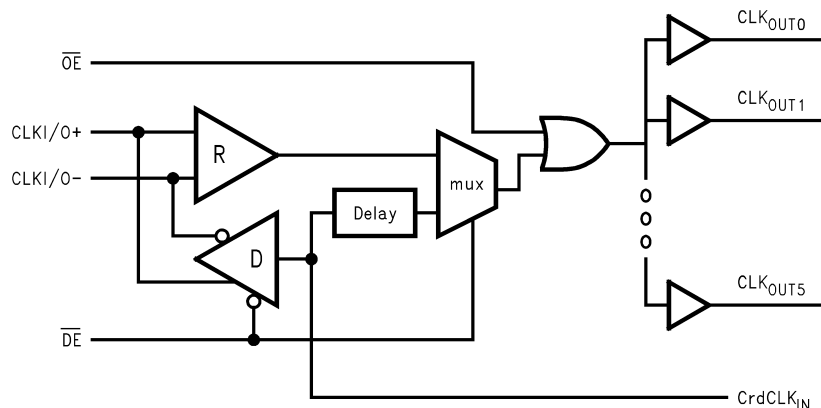


Table 1. Receive Mode Truth Table

INPUT				OUTPUT
\overline{OE}	\overline{DE}	$CrdCLK_{IN}$	$(CLKI/O+)-(CLKI/O-)$	CLK_{OUT}
H	H	X	X	H
L	H	X	$VID \geq 0.07V$	H
L	H	X	$VID \leq -0.07V$	L



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

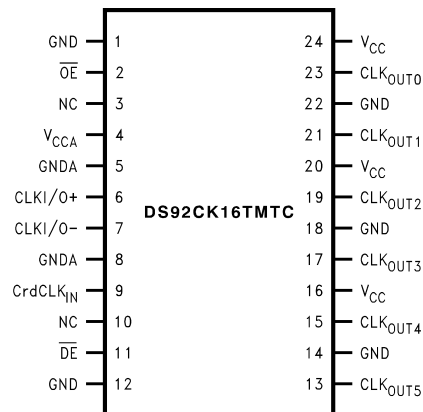
All trademarks are the property of their respective owners.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 1999–2013, Texas Instruments Incorporated

Table 2. Driver Mode Truth Table

INPUT			OUTPUT		
\overline{OE}	\overline{DE}	CrdCLK _{IN}	CLKI/O+	CLKI/O–	CLK _{OUT}
L	L	L	L	H	L
L	L	H	H	L	H
H	L	L	L	H	H
H	L	H	H	L	H
H	H	X	Z	Z	H

Connection Diagram

TSSOP Package
See Package Number PW (R-PDSO-G24)

TSSOP PACKAGE PIN DESCRIPTIONS

Pin Name	Pin #	Type	Description
CLKI/O+	6	I/O	True (Positive) side of the differential clock input.
CLKI/O–	7	I/O	Complementary (Negative) side of the differential clock input.
OE	2	I	\overline{OE} ; this pin is active Low. When High, this pin forces all CLK _{OUT} pins High. When Low, CLK _{OUT} pins logic state is determined by either the CrdCLK _{IN} or the VID at the CLKI/O pins with respect to the logic level at the \overline{DE} pin. This pin has a weak pullup device to V _{CC} . If \overline{OE} is floating, then all CLK _{OUT} pins will be High.
DE	11	I	\overline{DE} ; this pin is active LOW. When Low, this pin enables the CardCLK _{IN} signal to the CLKI/O pins and CLK _{OUT} pins. When High, the Driver is TRI-STATE, the CLKI/O pins are inputs and determine the state of the CLK _{OUT} pins. This pin has a weak pullup device to V _{CC} . If \overline{DE} is floating, then CLKI/O pins are TRI-STATE.
CLK _{OUT}	13, 15, 17, 19, 21, 23	O	6 Buffered clock (CMOS) outputs.
CrdCLK _{IN}	9	I	Input clock from Card (CMOS level or TTL level).
V _{CC}	16, 20, 24	Power	V _{CC} ; Analog V _{CCA} (Internally separate from V _{CC} , connect externally or use separate power supplies). No special power sequencing required. Either V _{CCA} or V _{CC} can be applied first, or simultaneously apply both power supplies.
GND	1, 12, 14, 18, 22	Ground	GND
V _{CCA}	4	Power	Analog V _{CCA} (Internally separate from V _{CC} , connect externally or use separate power supplies). No special power sequencing required. Either V _{CCA} or V _{CC} can be applied first, or simultaneously apply both power supplies.
GNDA	5, 8	Ground	Analog Ground (Internally separate from Ground must be connected externally).
NC	3, 10		No Connects



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾⁽²⁾

Supply Voltage (V_{CC})	-0.3V to +4V
Enable Input Voltage (\overline{DE} , \overline{OE} , CrCLK_{IN})	-0.3V to +4V
Voltage (CLK_{OUT})	-0.3V to ($V_{CC} + 0.3V$)
Voltage ($\text{CLKI}/O\pm$)	-0.3V to +4V
Driver Short Circuit Current	momentary
Receiver Short Circuit Current	momentary
Maximum Package Power Dissipation at +25°C	
PW Package	1500 mW
Derate PW Package	8.2 mW/°C above +25°C
θ_{JA}	95°C/W
θ_{JC}	30°C/W
Storage Temperature Range	-65°C to +150°C
Lead Temperature Range	
(Soldering, 4 sec.)	260°C
ESD Ratings: HBM ⁽³⁾	>3000V
CDM ⁽³⁾	>1000V
Machine Model ⁽³⁾	>200V

- (1) "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be verified. These ratings are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" specifies conditions of device operation.
- (2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/ Distributors for availability and specifications.
- (3) ESD Rating: ESD qualification is performed per the following: HBM (1.5 kΩ, 100 pF), Machine Model (250V, 0Ω), IEC 1000-4-2. All VCC pins connected together, all ground pins connected together.

Recommended Operating Conditions

	Min	Typ	Max	Units
Supply Voltage (V_{CC})	+3.0	+3.3	+3.6	V
CrCLK_{IN} , \overline{DE} , \overline{OE} Input Voltage	0		V_{CC}	V
Operating Free Air Temperature (T_A)	-40	25	+85	°C

DC Electrical Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified ^{(1) (2)}.

Symbol	Parameter	Conditions	Pin	Min	Typ	Max	Units
V_{TH}	Input Threshold High		CLKI/O+, CLKI/O-		25	+70	mV
V_{TL}	Input Threshold Low			-70	-35		mV
V_{CMR}	Common Mode Voltage Range ⁽³⁾	VID = 250 mV pk to pk		VID /2		2.4 - VID /2	V
I_{IN}	Input Current	$V_{IN} = 0V$ to V_{CC} , $\overline{DE} = V_{CC}$, $\overline{OE} = V_{CC}$, Other Input = 1.2V ± 50 mV		-20	±5	+20	μA

- (1) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except VID, VOD, VTH, and VTL.
- (2) All typicals are given for: $V_{CC} = +3.3V$ and $T_A = +25^\circ C$.
- (3) The VCMR range is reduced for larger VID. Example: If VID=400 mV, then VCMR is 0.2V to 2.2V A VID up to $|V_{CC}-0V|$ may be applied between the CLKI/O+ and CLKI/O- inputs, with the Common Mode set to $V_{CC}/2$.

DC Electrical Characteristics (continued)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified ⁽¹⁾ ⁽²⁾.

Symbol	Parameter	Conditions	Pin	Min	Typ	Max	Units
V _{OH1R}	Output High Voltage	VID = 250 mV, I _{OH} = -1.0 mA	CLK _{OUT}	V _{CC} -0.4	2.9		V
V _{OH2R}	Output High Voltage	VID = 250 mV, I _{OH} = -6 mA		V _{CC} -0.8	2.5		V
V _{OL1R}	Output Low Voltage	I _{OL} = 1.0 mA, VID = -250 mV			0.06	0.3	V
V _{OL2R}	Output Low Voltage	I _{OL} = 6 mA, VID = -250 mV		0		0.4	V
I _{ODHR}	CLK _{OUT} Dynamic Output Current ⁽⁴⁾	VID = +250 mV, V _{OUT} = V _{CC} -1V		-8	-16	-30	mA
I _{ODLR}	CLK _{OUT} Dynamic Output Current ⁽⁴⁾	VID = -250 mV, V _{OUT} = 1V		10	21	35	mA
V _{IH}	Input High Voltage		\overline{DE} , \overline{OE} , CrdCLK _{IN}	2.0		V _{CC}	V
V _{IL}	Input Low Voltage			GND		0.8	V
I _{IH}	Input High Current	V _{IN} = V _{CC} or 2.4V	\overline{OE} , \overline{DE}	-10	-2	+10	μA
I _{IL}	Input Low Current	V _{IN} = GND or 0.4V		-20	-5	+20	μA
I _{INCRD}	Input Current	V _{IN} = 0V to V _{CC} , \overline{OE} = V _{CC}	CrdCLK _{IN}	-5		+5	μA
V _{CL}	Input Voltage Clamp	I _{OUT} = -1.5 mA	\overline{OE} , \overline{DE} , CrdCLK _{IN}	-0.8			V
I _{CC}	No Load Supply Current Outputs Enabled, No VID Applied	\overline{OE} = \overline{DE} = 0V, CrdCLK _{IN} = V _{CC} or GND, CLKI/O (±) = Open CLK _{OUT} (0:5) = Open Circuit	V _{CC}			13	mA
I _{CC1}	No Load Supply Current Outputs Enabled, VID over Common Mode Voltage Range	\overline{OE} = GND \overline{DE} = V _{CC} CrdCLK _{IN} = V _{CC} or GND, VID = 250 mV (0.125V VCM 2.275V), CLK _{OUT} (0:5) = Open Circuit				10	mA
I _{CCD}	Driver Loaded Supply Current	\overline{DE} = \overline{OE} = 0V, CrdCLK _{IN} = V _{CC} or GND, R _L = 37.5Ω between CLKI/O+ and CLKI/O-, CLK _{OUT} (0:5) = Open Circuit			20	25	mA
V _{OD}	Driver Output Differential Voltage	R _L = 37.5Ω, Figure 5 \overline{DE} = 0V	CLKI/O+, CLKI/O-	250	350	450	mV
ΔV _{OD}	Driver V _{OD} Magnitude Change				10	20	mV
V _{OS}	Driver Offset Voltage			1.1	1.29	1.5	V
ΔV _{OS}	Driver Offset Voltage Magnitude Change				5	20	mV
V _{OHd}	Driver Output High				1.35	1.8	V
V _{OLD}	Driver Output Low			0.80	1.05		V
I _{OS1D}	Driver Differential Short Circuit Current ⁽⁵⁾	CrdCLK _{IN} = V _{CC} or GND, V _{OD} = 0V, (outputs shorted together) \overline{DE} = 0V			30	50	mA
I _{OS2D}	Driver Output Short Circuit Current to V _{CC} ⁽⁵⁾	CrdCLK _{IN} = GND, \overline{DE} = 0V, CLKI/O+ = V _{CC}			36	70	mA
I _{OS3D}	Driver Output Short Circuit Current to V _{CC} ⁽⁵⁾	CrdCLK _{IN} = V _{CC} , \overline{DE} = 0V, CLKI/O- = V _{CC}			34	70	mA
I _{OS4D}	Driver Output Short Circuit Current to GND ⁽⁵⁾	CrdCLK _{IN} = V _{CC} , \overline{DE} = 0V, CLKI/O+ = 0V			-47	-70	mA
I _{OS5D}	Driver Output Short Circuit Current to GND ⁽⁵⁾	CrdCLK _{IN} = GND, \overline{DE} = 0V, CLKI/O- = 0V			-50	-70	mA
I _{OFF}	Power Off Leakage Current	V _{CC} = 0V or Open, V _{APPLIED} = 3.6V				±20	μA

(4) Only one output should be momentarily shorted at a time. Do not exceed package power dissipation rating.

(5) Only one output should be momentarily shorted at a time. Do not exceed package power dissipation rating.

Switching Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified ⁽¹⁾ ⁽²⁾.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
DIFFERENTIAL RECEIVER CHARACTERISTICS						
t_{PHLDR}	Differential Propagation Delay High to Low. CLKI/O to CLK _{OUT}	$C_L = 15\text{ pF}$ $V_{ID} = 250\text{ mV}$ Figure 1 Figure 2	1.3	2.8	3.8	ns
t_{PLHDR}	Differential Propagation Delay Low to High. CLKI/O to CLK _{OUT}		1.3	2.9	3.8	ns
t_{SK1R}	Duty Cycle Distortion ⁽³⁾ (pulse skew) $ t_{PLH} - t_{PHL} $			100	400	ps
t_{SK2R}	Channel to Channel Skew; Same Edge ⁽⁴⁾			30	80	ps
t_{SK3R}	Part to Part Skew ⁽⁵⁾				2.5	ns
t_{TLHR}	Transition Time Low to High ⁽⁶⁾ (20% to 80%)		0.4	1.4	2.4	ns
t_{THLR}	Transition Time High to Low ⁽⁶⁾ (80% to 20%)		0.4	1.3	2.2	ns
t_{PLHOER}	Propagation Delay Low to High (\overline{OE} to CLK _{OUT})	$C_L = 15\text{ pF}$ Figure 3 Figure 4	1.0	3	4.5	ns
t_{PHLOER}	Propagation Delay High to Low (\overline{OE} to CLK _{OUT})		1.0	3	4.5	ns
f_{MAX}	Maximum Operating Frequency ⁽⁷⁾		100	125		MHz
DIFFERENTIAL DRIVER TIMING REQUIREMENTS						
t_{PHLDD}	Differential Propagation Delay High to Low. CrdCLK _{IN} to CLKI/O	$C_L = 15\text{ pF}$ $R_L = 37.5\Omega$ Figure 6 Figure 7	0.5	1.8	2.5	ns
t_{PLHDD}	Differential Propagation Delay Low to High. CrdCLK _{IN} to CLKI/O		0.5	1.8	2.5	ns
t_{PHLCrd}	CrdCLK _{IN} to CLK _{OUT} Propagation Delay High to Low	$C_L = 15\text{ pF}$ Figure 8 Figure 9	2.0	4.5	6.0	ns
t_{PLHCrd}	CrdCLK _{IN} to CLK _{OUT} Propagation Delay Low to High		2.0	4.5	6.0	ns
t_{SK1D}	Duty Cycle Distortion (pulse skew) $ t_{PLH} - t_{PHL} $ ⁽⁸⁾				600	ps
t_{SK2D}	Differential Part-to-Part Skew ⁽⁹⁾				2.0	ns
t_{TLHD}	Differential Transition Time ⁽⁶⁾ (20% to 80%)		0.4	0.75	1.4	ns
t_{THLD}	Differential Transition Time ⁽⁶⁾ (80% to 20%)		0.4	0.75	1.4	ns
t_{PHZD}	Transition Time High to TRI-STATE. \overline{DE} to CLKI/O				10	ns
t_{PLZD}	Transition Time Low to TRI-STATE. \overline{DE} to CLKI/O	$V_{IN} = 0\text{V to } V_{CC}$ $C_L = 15\text{ pF}$ $R_L = 37.5\Omega$ Figure 10 Figure 11			10	ns
t_{PZHD}	Transition Time TRI-STATE to High. \overline{DE} to CLKI/O				32	ns
t_{PZLD}	Transition Time TRI-STATE to Low. \overline{DE} to CLKI/O				32	ns
f_{MAX}	Maximum Operating Frequency ⁽⁷⁾		100	125		MHz

(1) C_L includes probe and fixture capacitance.

(2) Generator waveform for all tests unless otherwise specified: $f = 25\text{ MHz}$, $Z_o = 50\Omega$, $t_r = 1\text{ ns}$, $t_f = 1\text{ ns}$ (10%–90%). To ensure fastest propagation delay and minimum skew, clock input edge rates should not be slower than 1 ns/V; control signals not slower than 3 ns/V. In general, the faster the input edge rate, the better the AC performance.

(3) t_{SK1R} is the difference in receiver propagation delay ($|t_{PLH} - t_{PHL}|$) of one device, and is the duty cycle distortion of the output at any given temperature and V_{CC} . The propagation delay specification is a device to device worst case over process, voltage and temperature.

(4) t_{SK2R} is the difference in receiver propagation delay between channels in the same device of any outputs switching in the same direction. This parameter is specified by design and characterization.

(5) t_{SK3R} , part-to-part skew, is the difference in receiver propagation delay between devices of any outputs switching in the same direction. This specification applies to devices over recommended operating temperature and voltage ranges, and across process distribution. t_{SK3R} is defined as Max–Min differential propagation delay. This parameter is specified by design and characterization.

(6) All device output transition times are based on characterization measurements and are specified by design.

(7) Generator input conditions: $t_r/t_f < 1\text{ ns}$, 50% duty cycle, differential (1.10V to 1.35V pk-pk). Output Criteria: 60%/40% duty cycle, $V_{OL}(\text{max}) 0.4\text{V}$, $V_{OH}(\text{min}) 2.7\text{V}$, Load = 7 pF (stray plus probes).

(8) t_{SK1D} is the difference in driver propagation delay ($|t_{PLH} - t_{PHL}|$) and is the duty cycle distortion of the CLKI/O outputs.

(9) t_{SK2D} part-to-part skew, is the difference in driver propagation delay between devices of any outputs switching in the same direction. This specification applies to devices over recommended operating temperature and voltage ranges, and across process distribution. t_{SK2D} is defined as Max–Min differential propagation delay.

PARAMETER MEASUREMENT INFORMATION

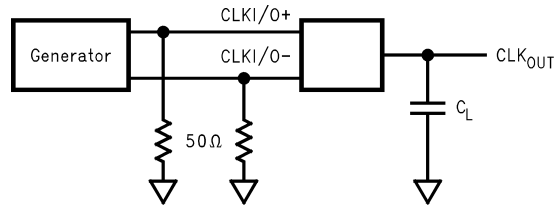
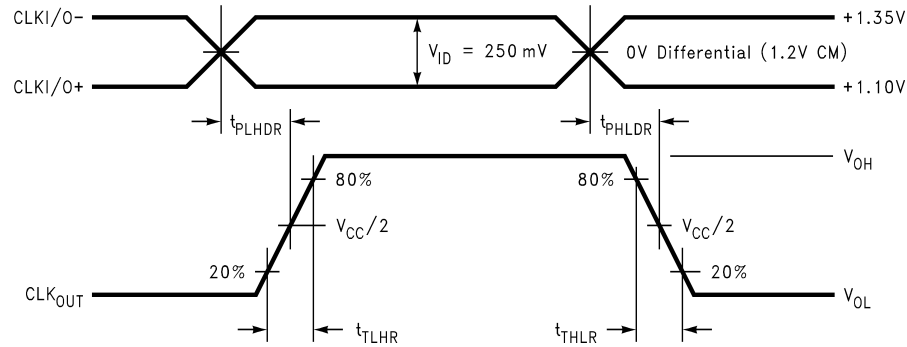


Figure 1. Receiver Propagation Delay and Transition Time Test Circuit



Generator waveform for all test unless otherwise specified: $f = 25 \text{ MHz}$, 50% Duty Cycle, $Z_o = 50\Omega$, $t_{TLH} = 1 \text{ ns}$, $t_{THL} = 1 \text{ ns}$.

Figure 2. Receiver Propagation Delay and Transition Time Waveforms

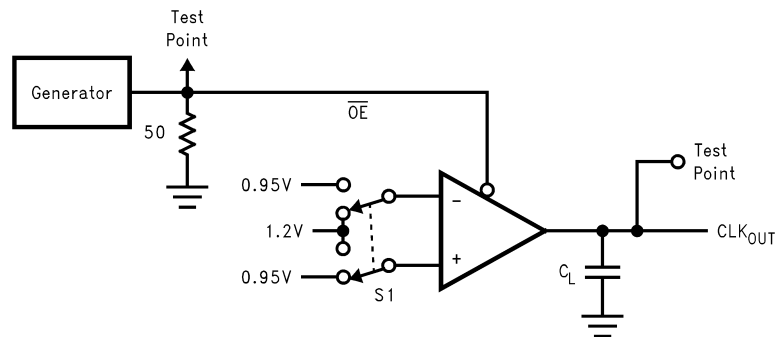


Figure 3. Output Enable (\overline{OE}) Delay Test Circuit

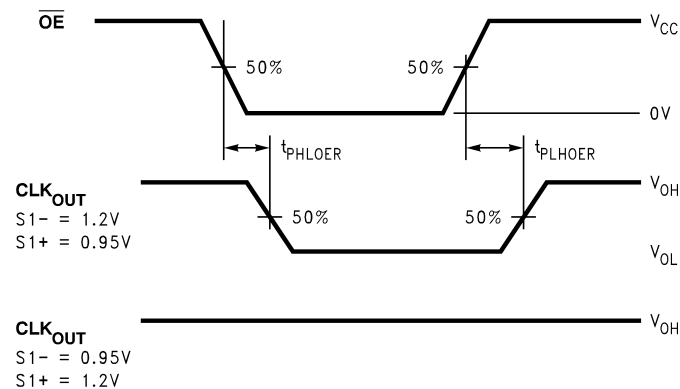


Figure 4. Output Enable (\overline{OE}) Delay Waveforms

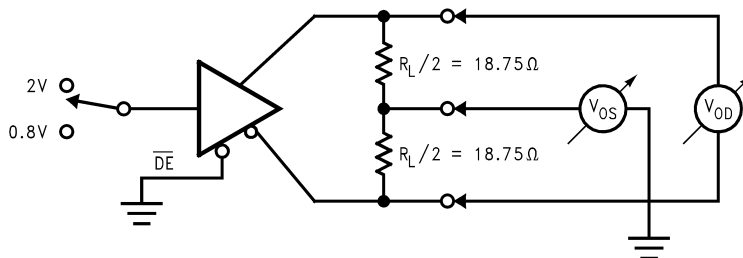


Figure 5. Differential Driver DC Test

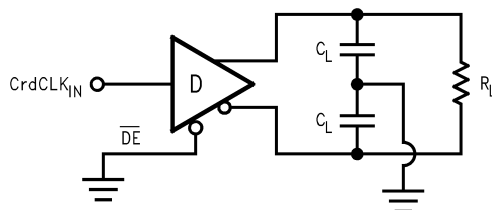


Figure 6. Driver Propagation Delay Test Circuit

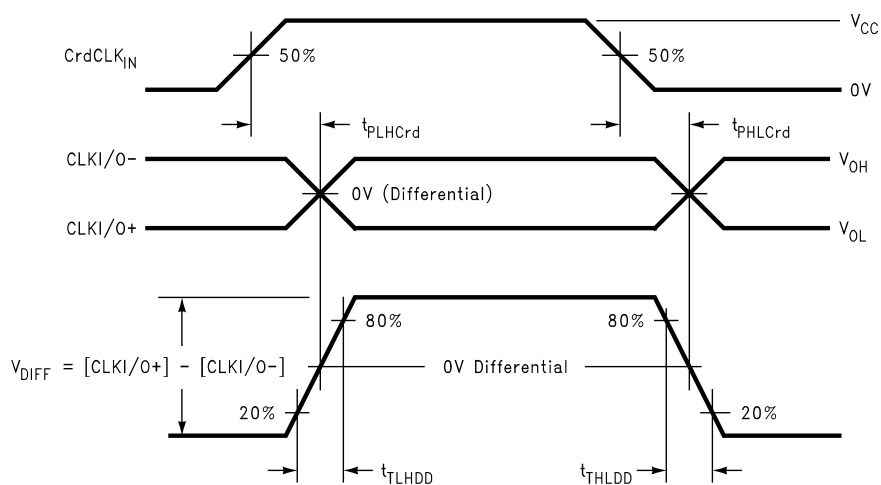


Figure 7. Driver Propagation Delay and Transition Time Waveforms

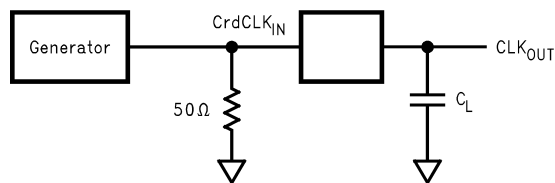


Figure 8. CrdCLK_IN Propagation Delay Time Test Circuit

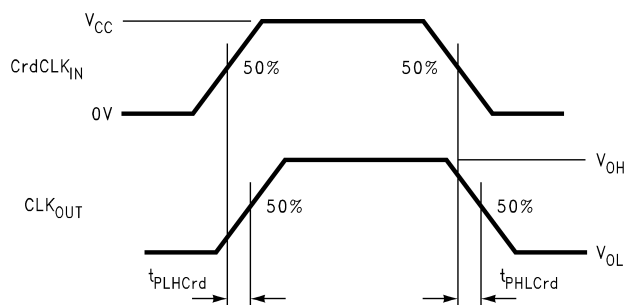


Figure 9. CrdCLK_IN Propagation Delay Time Waveforms

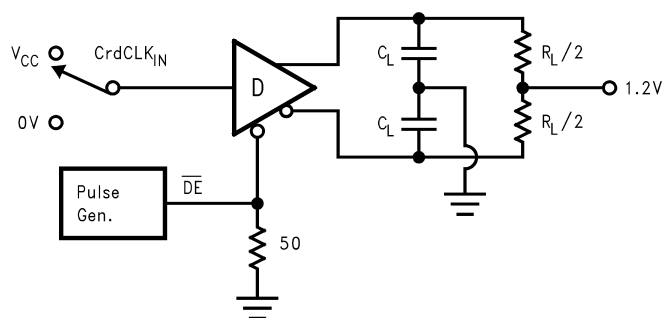


Figure 10. Driver TRI-STATE Test Circuit

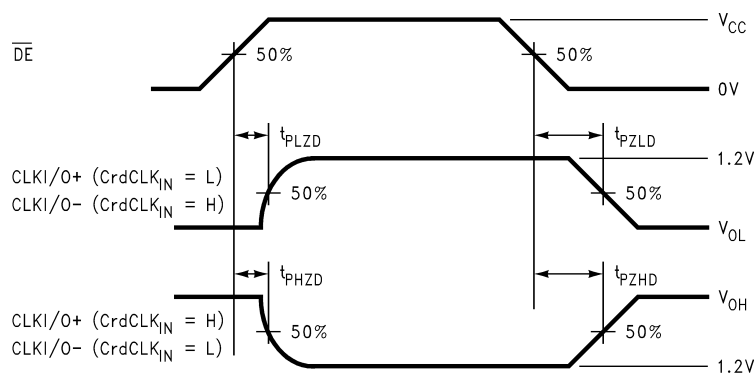


Figure 11. Driver TRI-STATE Waveforms

APPLICATIONS INFORMATION

General application guidelines and hints for BLVDS/LVDS transceivers, drivers and receivers may be found in the following application notes: LVDS Owner's Manual, AN805([SNOA233](#)), AN807([SNLA027](#)), AN808([SNLA028](#)), AN903([SNLA034](#)), AN905([SNLA035](#)), AN916([SNLA219](#)), AN971([SNLA165](#)), AN977([SNLA166](#)) .

BLVDS drivers and receivers are intended to be used in a differential backplane configuration. Transceivers or receivers are connected to the driver through a balanced media such as differential PCB traces. Typically, the characteristic differential impedance of the media (Z_0) is in the range of 50Ω to 100Ω. Two termination resistors of Z_0 each are placed at the ends of the transmission line backplane. The termination resistor converts the current sourced by the driver into a voltage that is detected by the receiver. The effects of mid-stream connector(s), cable stub(s), and other impedance discontinuities as well as ground shifting, noise margin limits, and total termination loading must be taken into account.

The DS92CK16 differential line driver is a balanced current source design. A current mode driver, generally speaking has a high output impedance (100 ohms) and supplies a constant current for a range of loads (a voltage mode driver on the other hand supplies a constant voltage for a range of loads). Current is switched through the load in one direction to produce a logic state and in the other direction to produce the other logic state. The output current is typically 9.330 mA. The current changes as a function of load resistor. The current mode **requires** (as discussed above) that a resistive termination be employed to terminate the signal and to complete the loop. Unterminated configurations are not allowed. The 9.33 mA loop current will develop a differential voltage of about 350mV across 37.5Ω (double terminated 75Ω differential transmission backplane) effective resistance, which the receiver detects with a 280 mV minimum differential noise margin neglecting resistive line losses (driven signal minus receiver threshold (350 mV – 70 mV = 280 mV)). The signal is centered around +1.2V (Driver Offset, V_{OS}) with respect to ground. Note that the steady-state voltage (V_{SS}) peak-to-peak swing is twice the differential voltage (V_{OD}) and is typically 700 mV.

The current mode driver provides substantial benefits over voltage mode drivers, such as an RS-422 driver. Its quiescent current remains relatively flat versus switching frequency. Whereas the RS-422 voltage mode driver increases exponentially in most case between 20 MHz–50 MHz. This is due to the overlap current that flows between the rails of the device when the internal gates switch. Whereas the current mode driver switches a fixed current between its output without any substantial overlap current. This is similar to some ECL and PECL devices, but without the heavy static I_{CC} requirements of the ECL/PECL designs. LVDS requires > 80% less current than similar PECL devices. AC specifications for the driver are a tenfold improvement over other existing RS-422 drivers.

The TRI-STATE function allows the driver outputs to be disabled, thus obtaining an even lower power state when the transmission of data is not required.

POWER DECOUPLING RECOMMENDATIONS

Bypass capacitors must be used on power pins. High frequency ceramic (surface mount is recommended) 0.1μF in parallel with 0.01μF, in parallel with 0.001μF at the power supply pin as well as scattered capacitors over the printed circuit board. Multiple vias should be used to connect the decoupling capacitors to the power planes. A 4.7μF (35V) or greater solid tantalum capacitor should be connected at the power entry point on the printed circuit board.

PC BOARD CONSIDERATIONS

Use at least 4 PCB layers (top to bottom); BLVDS signals, ground, power, TTL signals.

Isolate TTL signals from BLVDS signals, otherwise the TTL may couple onto the BLVDS lines. It is best to put TTL and BLVDS signals on different layers which are isolated by a power/ground plane(s).

Keep drivers and receivers as close to the (BLVDS port side) connectors as possible to create short stub lengths.

DIFFERENTIAL TRACES

Use controlled impedance traces which match the differential impedance of your transmission medium (ie. backplane or cable) and termination resistor(s). Run the differential pair trace lines as close together as possible as soon as they leave the IC. This will help eliminate reflections and ensure noise is coupled as common-mode. In fact, we have seen that differential signals which are 1mm apart radiate far less noise than traces 3mm apart since magnetic field cancellation is much better with the closer traces. Plus, noise induced on the differential lines is much more likely to appear as common-mode which is rejected by the receiver.

Match electrical lengths between traces to reduce skew. Skew between the signals of a pair means a phase difference between signals which destroys the magnetic field cancellation benefits of differential signals and EMI will result. (Note the velocity of propagation, $v = c/\epsilon_r$ where c (the speed of light) = 0.2997mm/ps or 0.0118 in/ps). Do not rely solely on the autoroute function for differential traces. Carefully review dimensions to match differential impedance and provide isolation for the differential lines. Minimize the number of vias and other discontinuities on the line.

Avoid 90° turns (these cause impedance discontinuities). Use arcs or 45° bevels.

Within a pair of traces, the distance between the two traces should be minimized to maintain common-mode rejection of the receivers. On the printed circuit board, this distance should remain constant to avoid discontinuities in differential impedance. Minor violations at connection points are allowable.

STUB LENGTH

Stub lengths should be kept to a minimum. The typical transition time of the DS92CK16 BLVDS output is 0.75ns (20% to 80%). The 100 percent time is 0.75/0.6 or 1.25ns. For a general approximation, if the electrical length of a trace is greater than 1/5 of the transition edge, then the trace is considered a transmission line. For example, 1.25ns/5 is 250 picoseconds. Let velocity equal 160ps per inch for a typical loaded backplane. Then maximum stub length is 250ps/160ps/in or 1.56 inches. To determine the maximum stub for your backplane, you need to know the propagation velocity for the actual conditions (refer to application notes AN-905([SNLA035](#)) and AN-808([SNLA028](#))).

TERMINATION

Use a resistor which best matches the differential impedance of your loaded transmission line. Remember that the current mode outputs need the termination resistor to generate the differential voltage. BLVDS will not work without resistor termination.

Surface mount 1% to 2% resistors are best.

PROBING BLVDS TRANSMISSION LINES

Always use high impedance ($> 100k\Omega$), low capacitance ($< 2pF$) scope probes with a wide bandwidth (1GHz) scope. Improper probing will give deceiving results.

CABLES AND CONNECTORS, GENERAL COMMENTS

Use controlled impedance media. The connectors you use should have a matched differential impedance of about $Z_0 \Omega$. They should not introduce major impedance discontinuities.

Balanced cables (e.g. twisted pair) are usually better than unbalanced cables (ribbon cable, simple coax.) for noise reduction and signal quality. Balanced cables tend to generate less EMI due to field canceling effects and also tend to pick up electromagnetic radiation a common-mode (not differential mode) noise which is rejected by the receiver. For cable distances $< 0.5M$, most cables can be made to work effectively. For distances $0.5M \leq d \leq 10M$, CAT 3 (category 3) twisted pair cable works well, is readily available and relatively inexpensive.

REVISION HISTORY

Changes from Revision B (April 2013) to Revision C	Page
• Changed layout of National Data Sheet to TI format	10

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DS92CK16TMT	ACTIVE	TSSOP	PW	24	61	TBD	Call TI	Call TI	-40 to 85	DS92CK16T MTC	Samples
DS92CK16TMT/NOPB	ACTIVE	TSSOP	PW	24	61	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	DS92CK16T MTC	Samples
DS92CK16TMTX/NOPB	ACTIVE	TSSOP	PW	24	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	DS92CK16T MTC	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

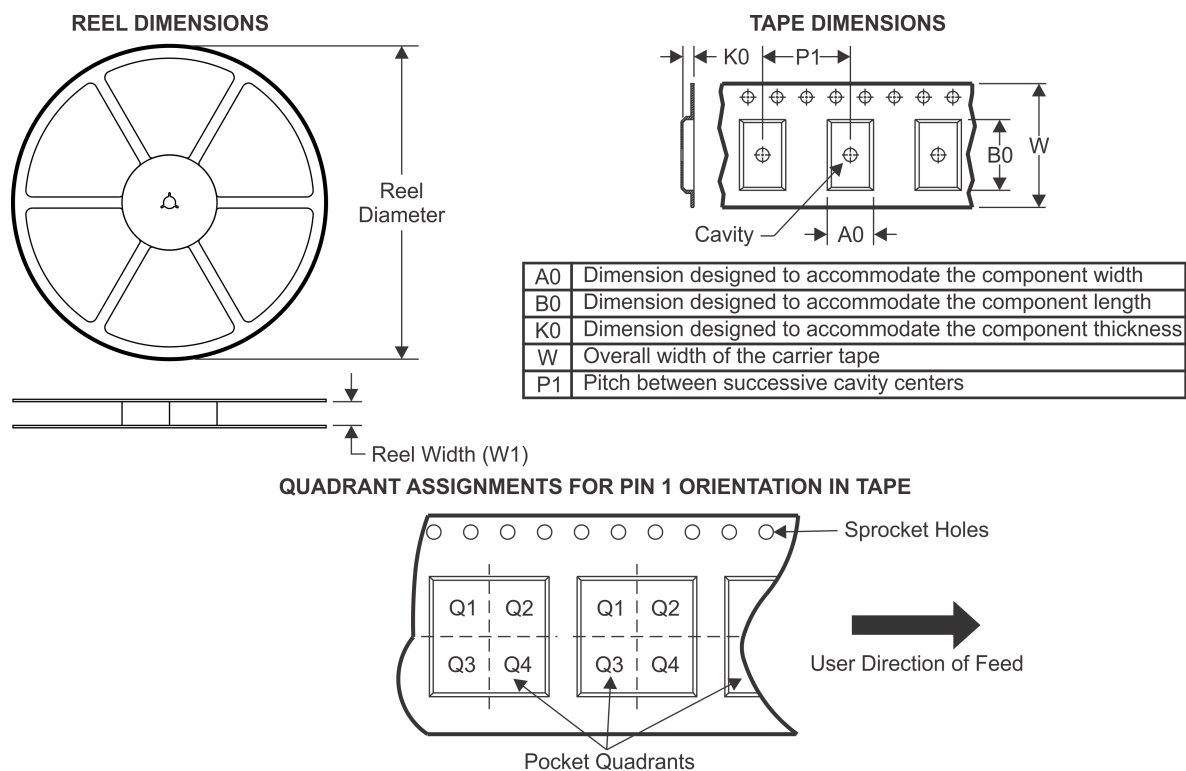
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

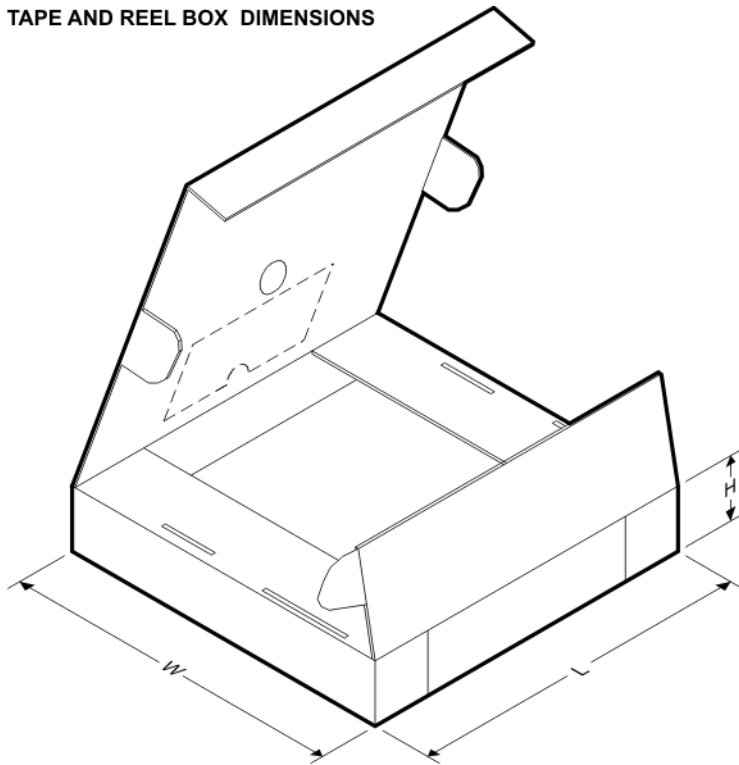
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS92CK16TMTX/NOPB	TSSOP	PW	24	2500	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

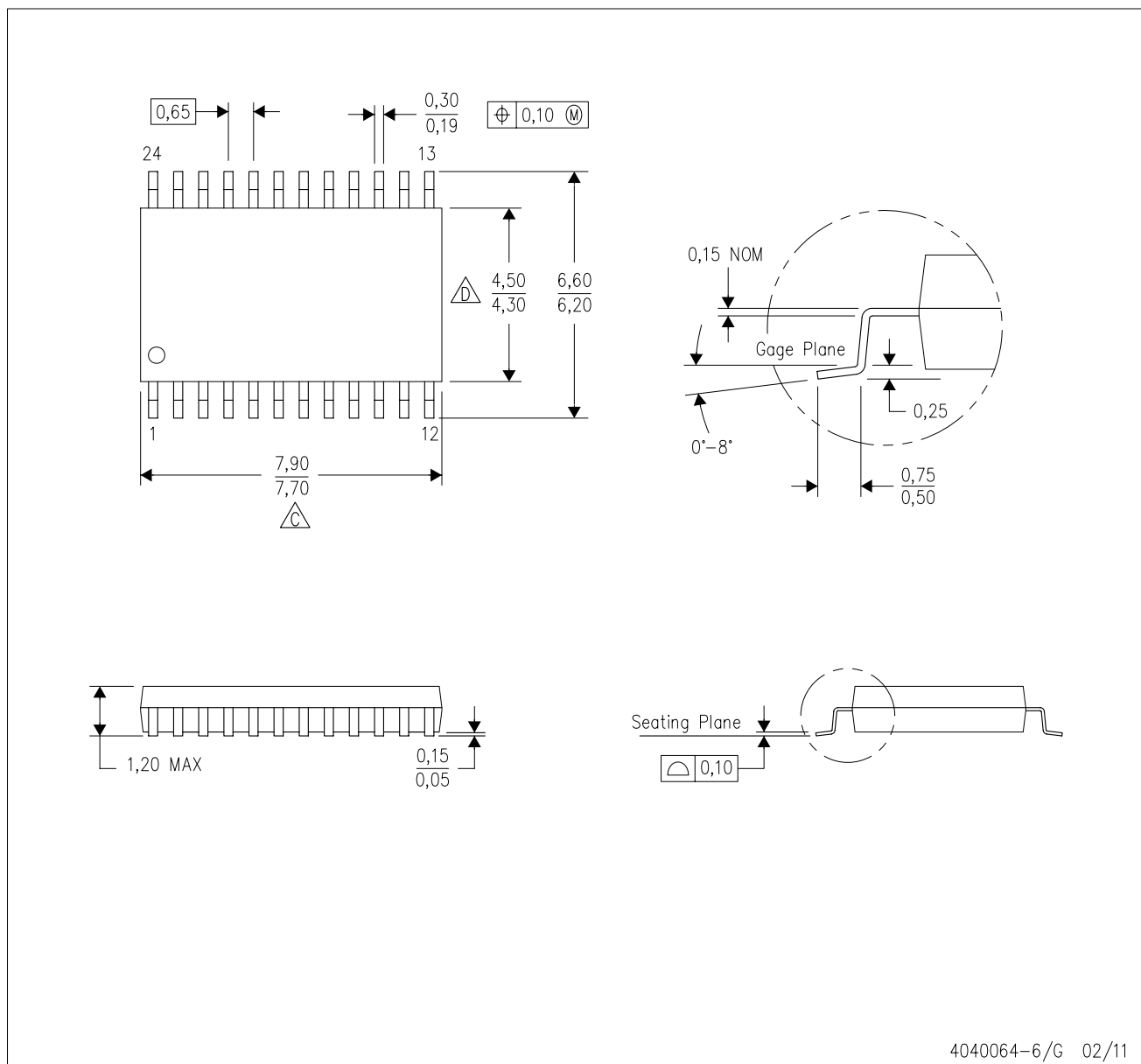


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS92CK16TMTX/NOPB	TSSOP	PW	24	2500	367.0	367.0	35.0

PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com